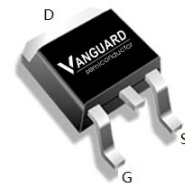


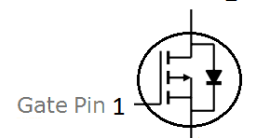
## Features

- P-Channel, -5V Logic Level Control
- Fast Switching
- Enhancement mode
- 100% Avalanche Tested
- Pb-free lead plating; RoHS compliant

$V_{DS}$	-40	V
$R_{DS(on),TYP} @ V_{GS}=-10V$	26	m $\Omega$
$R_{DS(on),TYP} @ V_{GS}=-4.5V$	42	m $\Omega$
$I_D$	-33	A


**TO-252**


Drain Pin 2



Source Pin 3

Part ID	Package Type	Marking	Tape and reel information
VS4518AD	TO-252	4518AD	2500PCS/Reel

### Maximum ratings, at $T_j = 25^\circ\text{C}$ , unless otherwise specified

Symbol	Parameter	Rating	Unit	
$V_{(BR)DSS}$	Drain-Source breakdown voltage	-40	V	
$I_S$	Diode continuous forward current	$T_C = 25^\circ\text{C}$ -33	A	
$I_D$	Continuous drain current @ $V_{GS} = -10V$	$T_C = 25^\circ\text{C}$	-33	A
		$T_C = 100^\circ\text{C}$	-23	A
$I_{DM}$	Pulse drain current tested ①	$T_C = 25^\circ\text{C}$ -132	A	
EAS	Avalanche energy, single pulsed ②	68	mJ	
$P_D$	Maximum power dissipation	$T_C = 25^\circ\text{C}$ 48	W	
$V_{GS}$	Gate-Source voltage	$\pm 20$	V	
$T_{STG} T_J$	Storage and operating temperature range	-55 to 175	$^\circ\text{C}$	
<b>Thermal Characteristics</b>				
$R_{\theta JC}$	Thermal Resistance-Junction to Case	3.1	$^\circ\text{C/W}$	
$R_{\theta JA}$	Thermal Resistance-Junction to Ambient	100	$^\circ\text{C/W}$	

Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>Static Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =-250μA	-40	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	--	--	-1	μA
	Zero Gate Voltage Drain Current(T <sub>J</sub> =125°C)	V <sub>DS</sub> =-40V, V <sub>GS</sub> =0V	--	--	-100	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(TH)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250μA	-1.3	-1.8	-2.4	V
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance ③	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	--	26	34	mΩ
R <sub>DS(ON)</sub>	Drain-Source On-State Resistance ③	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-15A	--	42	55	mΩ
<b>Dynamic Electrical Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
C <sub>iss</sub>	Input Capacitance	V <sub>DS</sub> =-20V, V <sub>GS</sub> =0V, f=1MHz	1100	1310	1500	pF
C <sub>oss</sub>	Output Capacitance		65	115	165	pF
C <sub>rss</sub>	Reverse Transfer Capacitance		50	90	130	pF
R <sub>g</sub>	Gate Resistance	f=1MHz	--	9.5	--	Ω
Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =-20V, I <sub>D</sub> =-20A, V <sub>GS</sub> =-10V	--	30	--	nC
Q <sub>gs</sub>	Gate-Source Charge		--	4	--	nC
Q <sub>gd</sub>	Gate-Drain Charge		--	6	--	nC
<b>Switching Characteristics</b>						
t <sub>d(on)</sub>	Turn-on Delay Time	V <sub>DD</sub> =-20V, I <sub>D</sub> =-20A, R <sub>G</sub> =3.0Ω, V <sub>GS</sub> =-10V	--	9	--	nS
t <sub>r</sub>	Turn-on Rise Time		--	7	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	192	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	64	--	nS
<b>Source- Drain Diode Characteristics @ T<sub>J</sub> = 25°C (unless otherwise stated)</b>						
V <sub>SD</sub>	Forward on voltage	I <sub>SD</sub> =-20A, V <sub>GS</sub> =0V	--	-1	-1.2	V
t <sub>rr</sub>	Reverse Recovery Time	T <sub>J</sub> =25°C, I <sub>sd</sub> =-20A, V <sub>GS</sub> =0V	--	17	--	nS
Q <sub>rr</sub>	Reverse Recovery Charge		di/dt=-100A/μs		7	

**NOTE:**

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Limited by T<sub>Jmax</sub>, starting T<sub>J</sub> = 25°C, L = 0.5mH, R<sub>G</sub> = 25Ω, I<sub>AS</sub> = -13A, V<sub>GS</sub> = -10V. Part not recommended for use above this value
- ③ Pulse width ≤ 300μs; duty cycles ≤ 2%.

Typical Characteristics

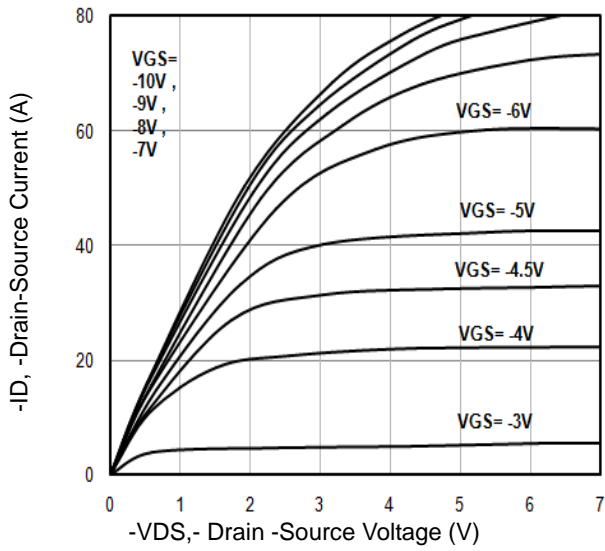


Fig1. Typical Output Characteristics

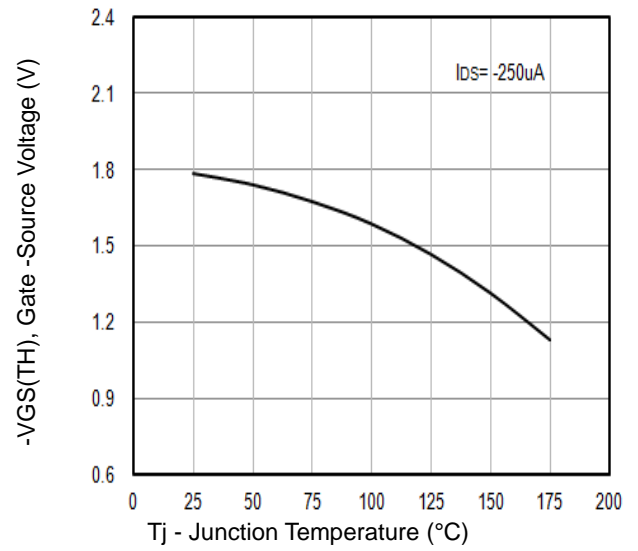


Fig2. -VGS(TH) Gate -Source Voltage Vs. Tj

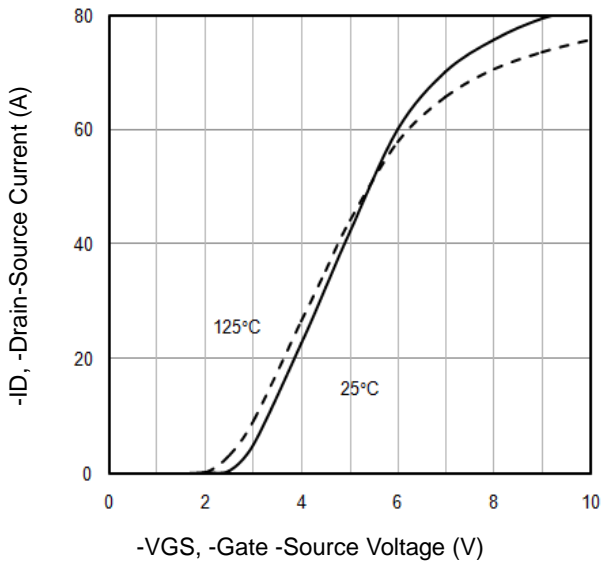


Fig3. Typical Transfer Characteristics

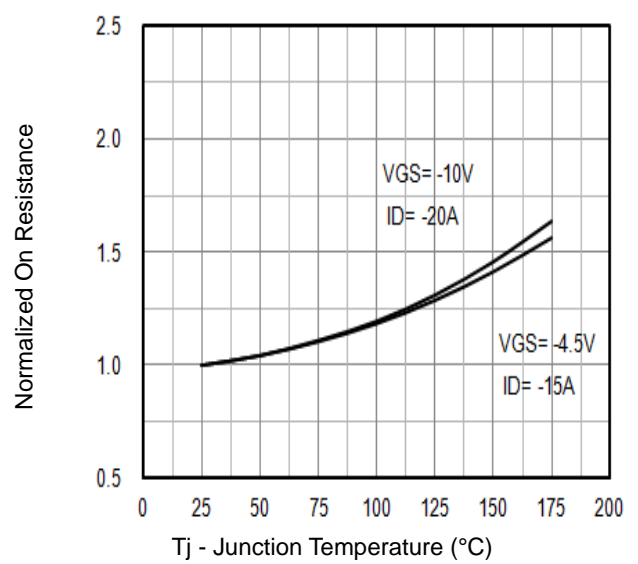


Fig4. Normalized On-Resistance Vs. Tj

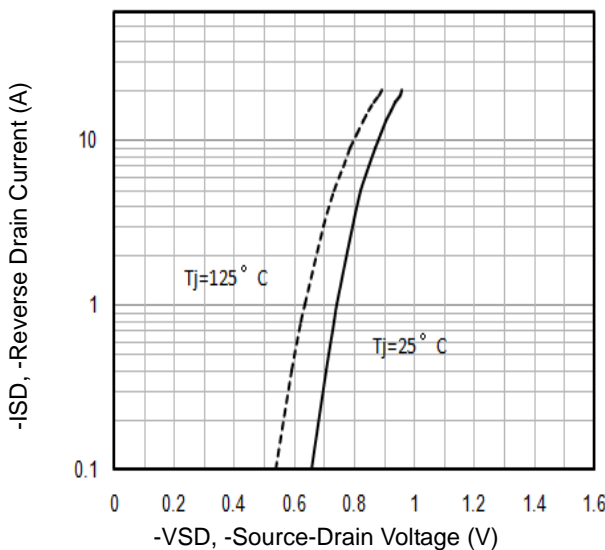


Fig5. Typical Source-Drain Diode Forward Voltage

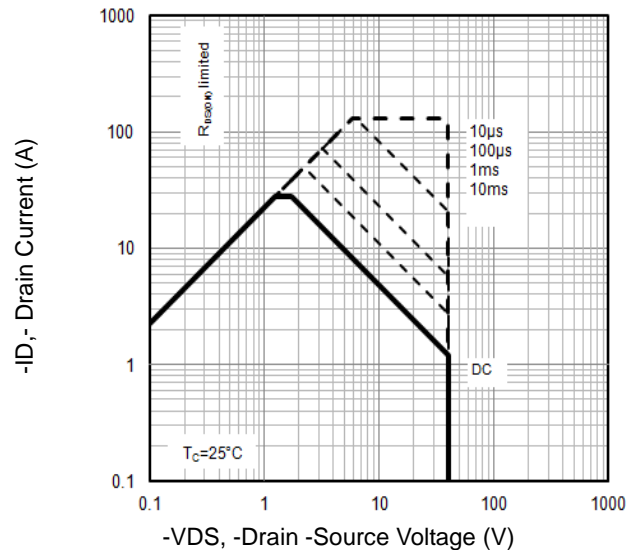


Fig6. Maximum Safe Operating Area

Typical Characteristics

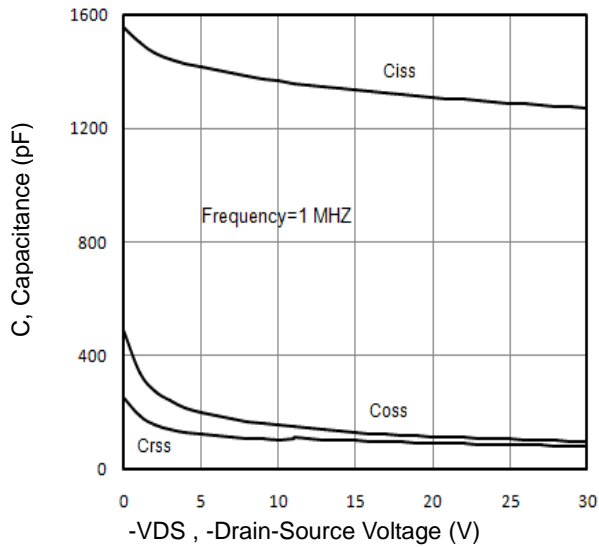


Fig7. Typical Capacitance Vs.Drain-Source Voltage

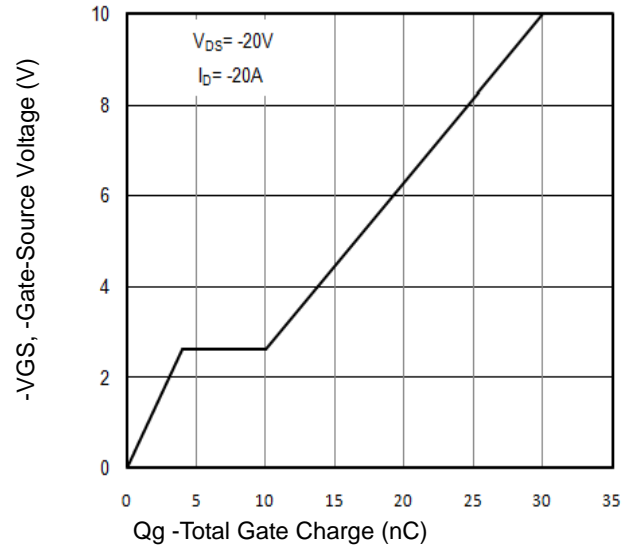


Fig8. Typical Gate Charge Vs.Gate-Source Voltage

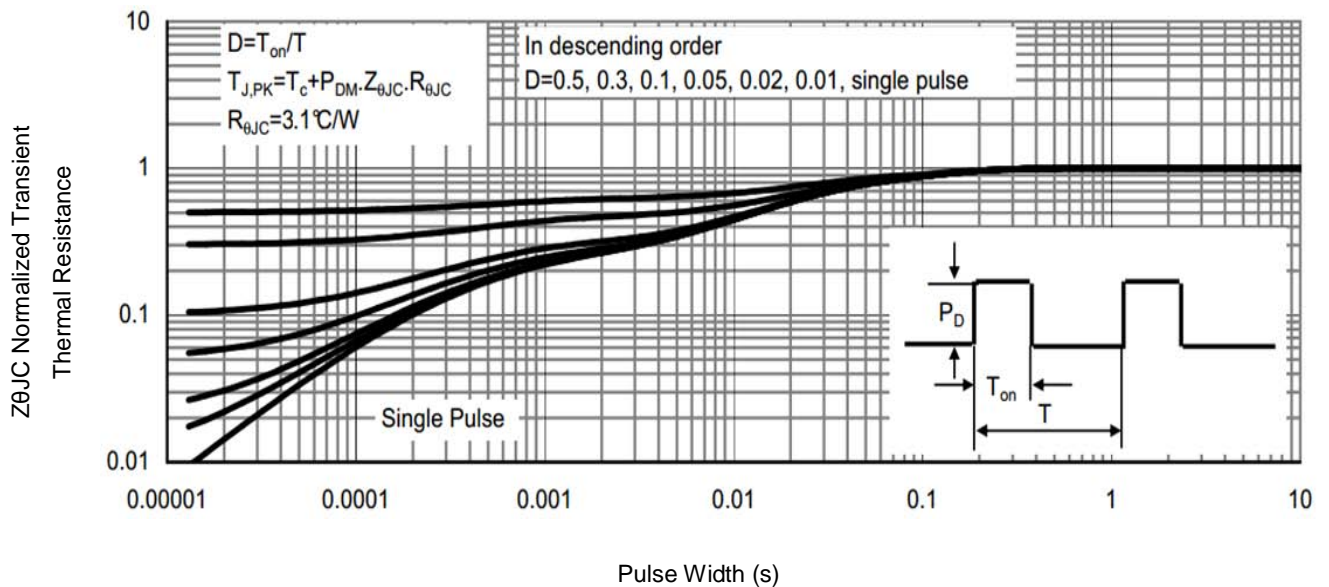


Fig9. Normalized Maximum Transient Thermal Impedance

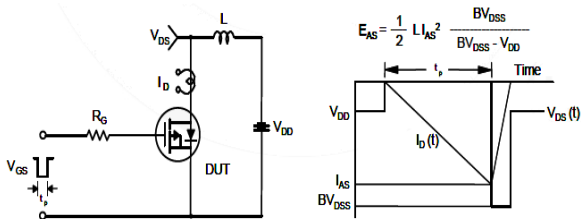


Fig10. Unclamped Inductive Test Circuit and Waveforms

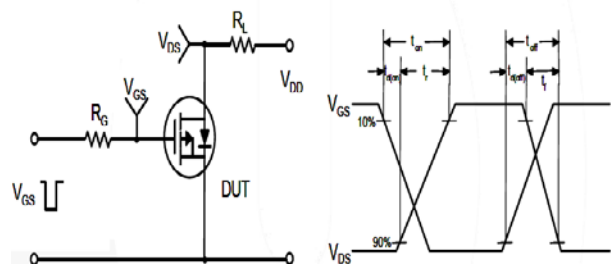
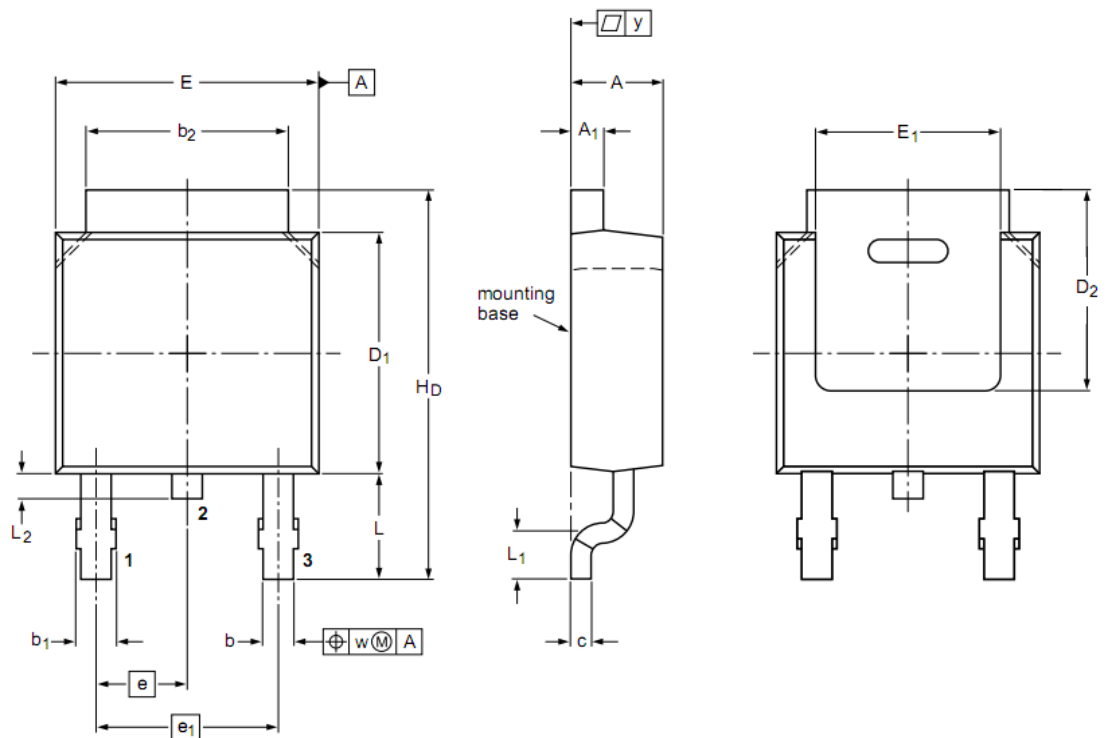


Fig11. Switching Time Test Circuit and waveforms

### TO-252 Package Outline Data



Symbol	Dimensions (unit: mm)		
	Min	Typ	Max
A	2.20	2.30	2.38
A <sub>1</sub>	0.46	0.50	0.63
b	0.64	0.76	0.89
b <sub>1</sub>	0.77	0.85	1.14
b <sub>2</sub>	5.00	5.33	5.46
c	0.458	0.508	0.558
D <sub>1</sub>	5.98	6.10	6.223
D <sub>2</sub>	5.21	--	--
E	6.40	6.60	6.731
E <sub>1</sub>	4.40	--	--
e	2.286 BSC		
e <sub>1</sub>	--	4.57	--
H <sub>D</sub>	9.40	10.00	10.40
L	2.743 REF		
L <sub>1</sub>	1.40	1.52	1.77
L <sub>2</sub>	0.50	0.80	1.01
w	--	0.20	--
y	--	--	0.20

#### Notes:

1. Refer to JEDEC TO-252 variation AA
2. Dimension "E" does NOT include mold flash, protrusions or gate burrs. Mold flash, protrusions or gate burrs shall not exceed 0.1524mm per side.
3. Dimension "D1" does NOT include interlead flash or protrusion. Interlead flash or protrusion shall not exceed 0.1524mm per end.

### Customer Service

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